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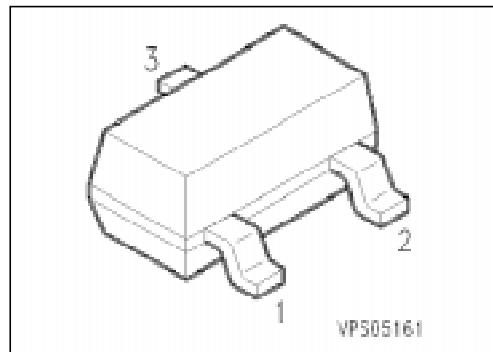
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NPN Silicon AF Transistors

BC 846 ... BC 850

Features

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30 Hz and 15 kHz
- Complementary types: BC 856, BC 857,
BC 859, BC 860 (PNP)



Type	Marking	Ordering Code (tape and reel)	Pin Configuration			Package ¹⁾
			1	2	3	
BC 846 A	1As	Q62702-C1772	B	E	C	SOT-23
BC 846 B	1Bs	Q62702-C1746				
BC 847 A	1Es	Q62702-C1884				
BC 847 B	1Fs	Q62702-C1687				
BC 847 C	1Gs	Q62702-C1715				
BC 848 A	1Js	Q62702-C1741				
BC 848 B	1Ks	Q62702-C1704				
BC 848 C	1Ls	Q62702-C1506				
BC 849 B	2Bs	Q62702-C1727				
BC 849 C	2Cs	Q62702-C1713				
BC 850 B	2Fs	Q62702-C1885				
BC 850 C	2Gs	Q62702-C1712				

¹⁾For detailed information see chapter Package Outlines.

Maximum Ratings

Parameter	Symbol	Values			Unit	
		BC 846	BC 847 BC 850	BC 848 BC 849		
Collector-emitter voltage	V_{CE0}	65	45	30	V	
Collector-base voltage	V_{CB0}	80	50	30		
Collector-emitter voltage	V_{CES}	80	50	30		
Emitter-base voltage	V_{EB0}	6	6	5		
Collector current	I_C	100			mA	
Peak collector current	I_{CM}	200				
Peak base current	I_{BM}	200				
Peak emitter current	I_{EM}	200				
Total power dissipation, $T_S = 71 \text{ } ^\circ\text{C}$	P_{tot}	330			mW	
Junction temperature	T_j	150			$^\circ\text{C}$	
Storage temperature range	T_{stg}	– 65 ... + 150				

Thermal Resistance

Junction - ambient ¹⁾	$R_{th JA}$	≤ 310	K/W
Junction - soldering point	$R_{th JS}$	≤ 240	

¹⁾Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm² Cu.

Electrical Characteristicsat $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC characteristics

Collector-emitter breakdown voltage $I_C = 10 \text{ mA}$	$V_{(\text{BR})\text{CEO}}$	65 45 30	— — —	— — —	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}$	$V_{(\text{BR})\text{CB0}}$	80 50 30	— — —	— — —	
Collector-emitter breakdown voltage $I_C = 10 \mu\text{A}, V_{BE} = 0$	$V_{(\text{BR})\text{CES}}$	80 50 30	— — —	— — —	
Emitter-base breakdown voltage $I_E = 1 \mu\text{A}$	$V_{(\text{BR})\text{EB0}}$	6 5	— —	— —	
Collector cutoff current $V_{CB} = 30 \text{ V}$ $V_{CB} = 30 \text{ V}, T_A = 150^\circ\text{C}$	I_{CBO}	— —	— —	15 5	nA μA
DC current gain $I_C = 10 \mu\text{A}, V_{CE} = 5 \text{ V}$	h_{FE}	— — —	140 250 480	— — —	—
$I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}$		110 200 420	180 290 520	220 450 800	
Collector-emitter saturation voltage ¹⁾ $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ $I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$	$V_{CE\text{sat}}$	— —	90 200	250 600	mV
Base-emitter saturation voltage ¹⁾ $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ $I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$	$V_{BE\text{sat}}$	— —	700 900	— —	
Base-emitter voltage $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}$ $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	$V_{BE(\text{on})}$	580 —	660 —	700 770	

¹⁾Pulse test: $t \leq 300 \mu\text{s}$, $D = 2\%$.

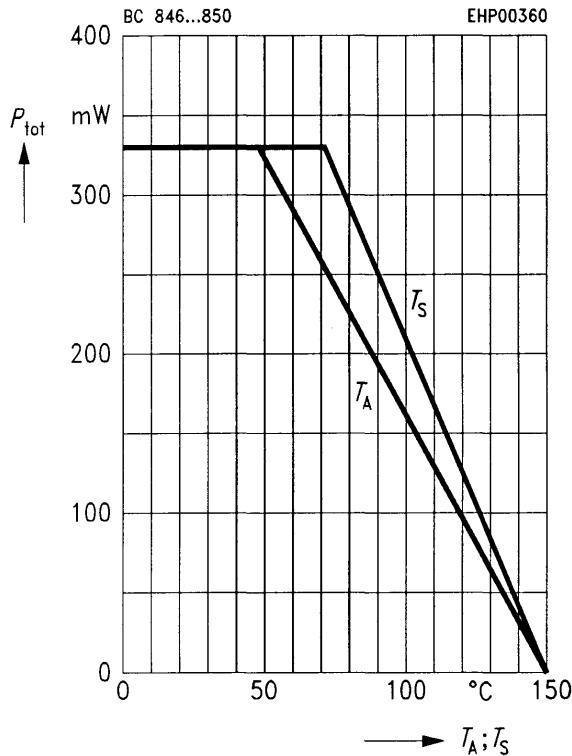
Electrical Characteristicsat $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

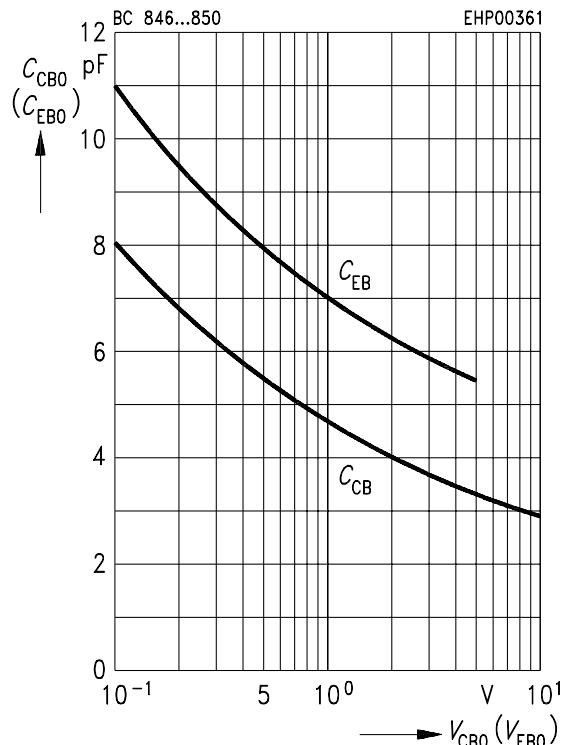
AC characteristics

Transition frequency $I_C = 20 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	f_T	—	250	—	MHz
Output capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{obo}	—	3	—	pF
Input capacitance $V_{CB} = 0.5 \text{ V}, f = 1 \text{ MHz}$	C_{ibo}	—	8	—	
Short-circuit input impedance $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	h_{11e}	—	2.7	—	kΩ
Open-circuit reverse voltage transfer ratio $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	h_{12e}	—	1.5	—	10^{-4}
Short-circuit forward current transfer ratio $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	h_{21e}	—	200	—	—
Open-circuit output admittance $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	h_{22e}	—	18	—	μS
Noise figure $I_C = 0.2 \text{ mA}, V_{CE} = 5 \text{ V}, R_S = 2 \text{ kΩ}$ $f = 30 \text{ Hz} \dots 15 \text{ kHz}$ BC 849 BC 850	F	—	1.4	4	dB
$f = 1 \text{ kHz}, \Delta f = 200 \text{ Hz}$ BC 849 BC 850		—	1.4	3	
Equivalent noise voltage $I_C = 0.2 \text{ mA}, V_{CE} = 5 \text{ V}, R_S = 2 \text{ kΩ}$ $f = 10 \text{ Hz} \dots 50 \text{ Hz}$ BC 850	V_n	—	1.2	4	
		—	1.0	4	
		—	0.135	μV	

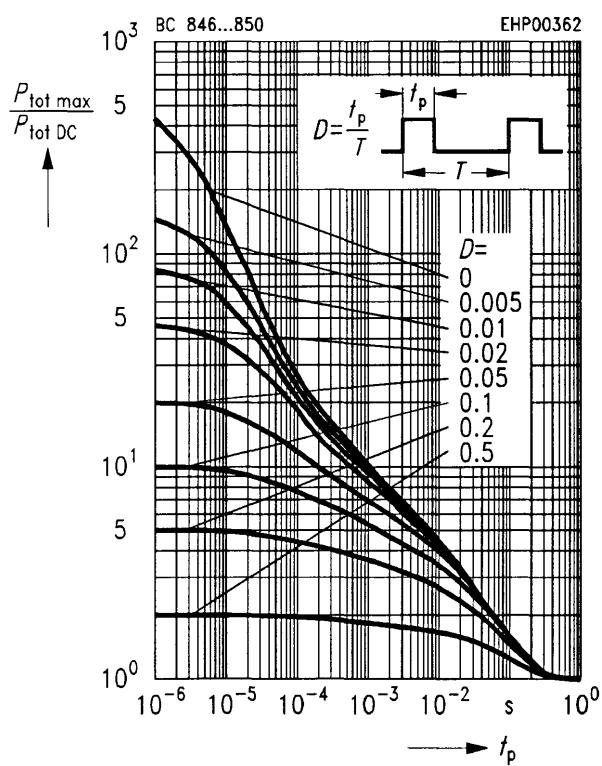
Total power dissipation $P_{\text{tot}} = f(T_A^*; T_S)$
 * Package mounted on epoxy



Collector-base capacitance $C_{CB0} = f(V_{CB0})$
Emitter-base capacitance $C_{EB0} = f(V_{EB0})$

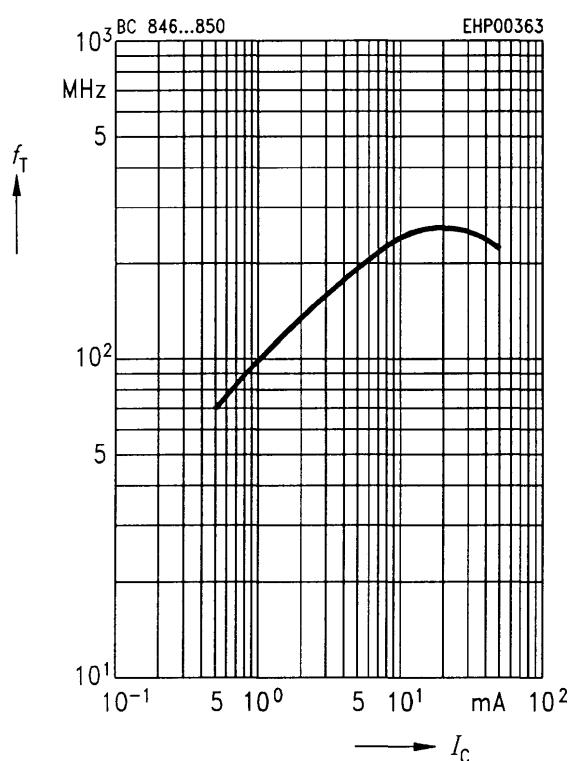


Permissible pulse load $P_{\text{tot max}}/P_{\text{tot DC}} = f(t_p)$

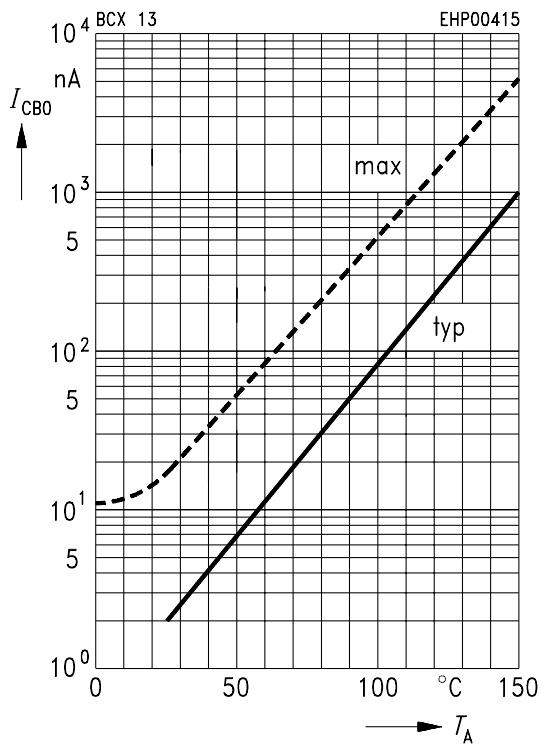


Transition frequency $f_T = f(I_C)$

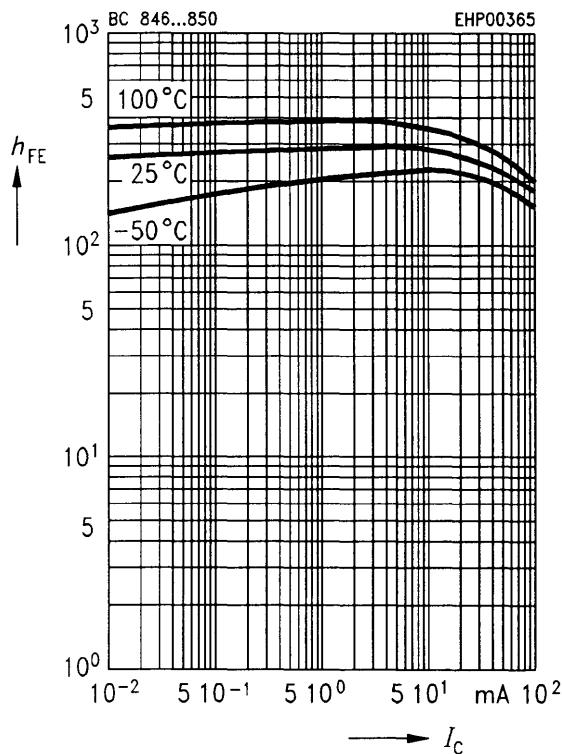
$V_{CE} = 5$ V



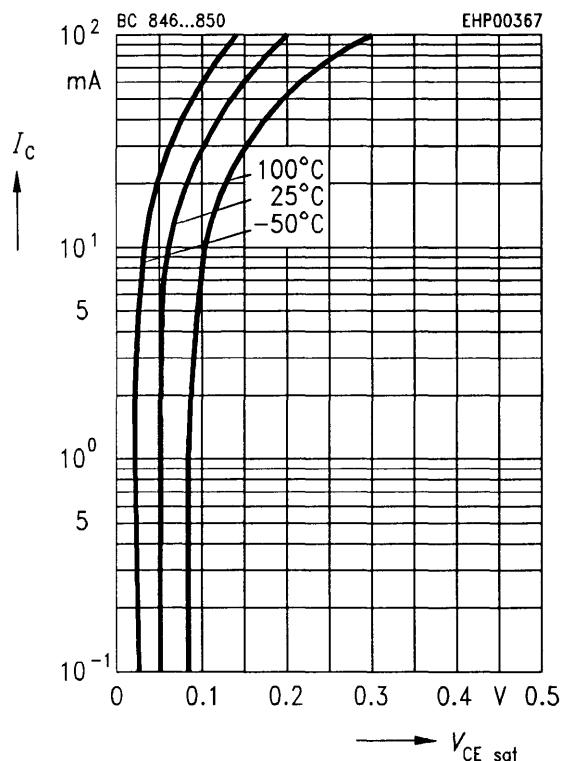
Collector cutoff current $I_{CB0} = f(T_A)$
 $V_{CB} = 30 \text{ V}$



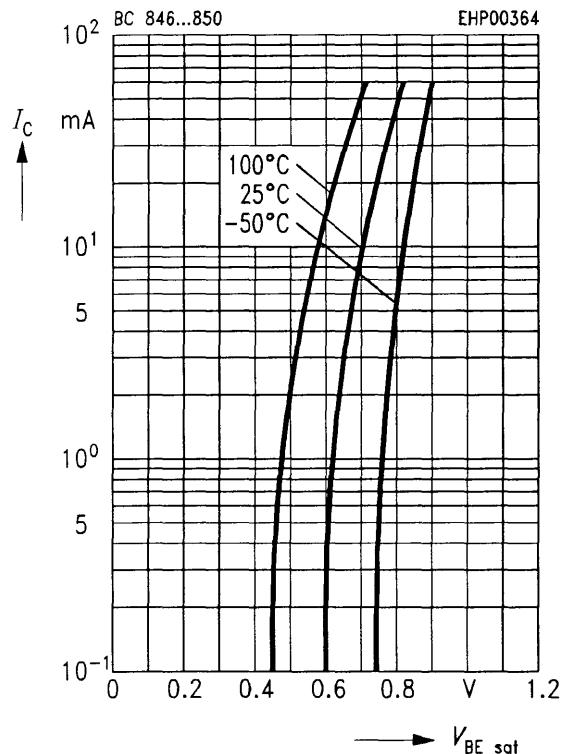
DC current gain $h_{FE} = f(I_C)$
 $V_{CE} = 5 \text{ V}$



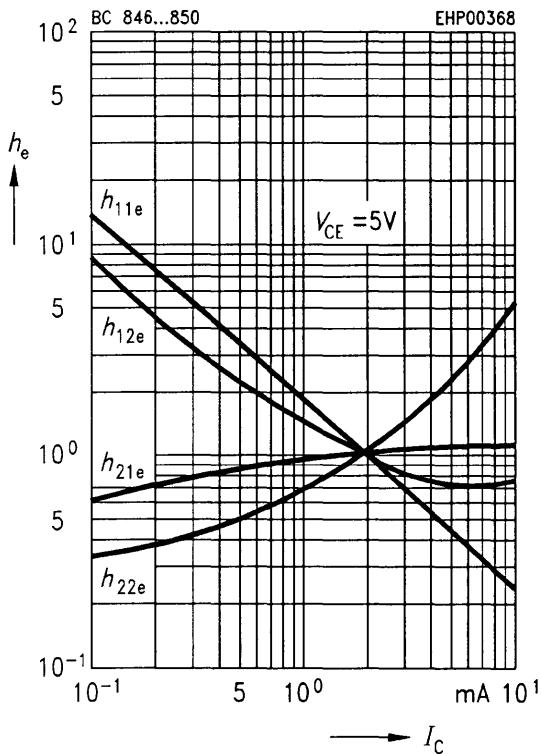
Collector-emitter saturation voltage
 $I_C = f(V_{CEsat}), h_{FE} = 20$



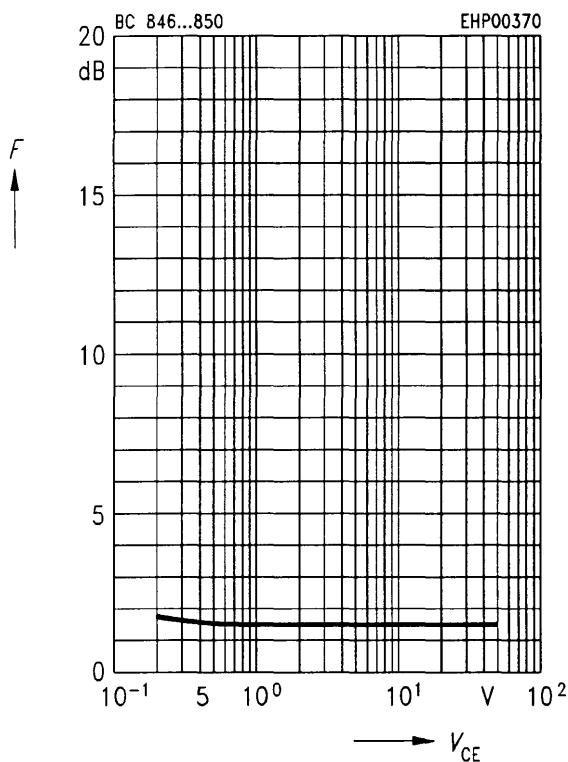
Base-emitter saturation voltage
 $I_C = f(V_{BESat}), h_{FE} = 20$



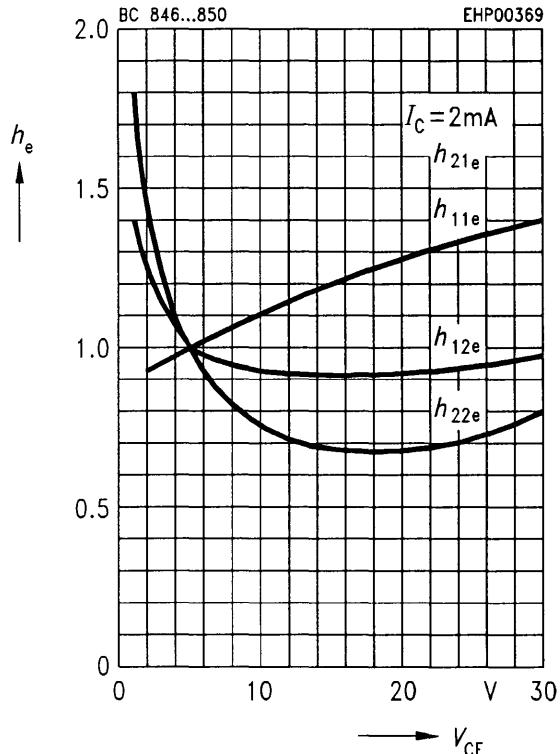
h parameter $h_e = f(I_c)$ normalized
 $V_{CE} = 5 \text{ V}$



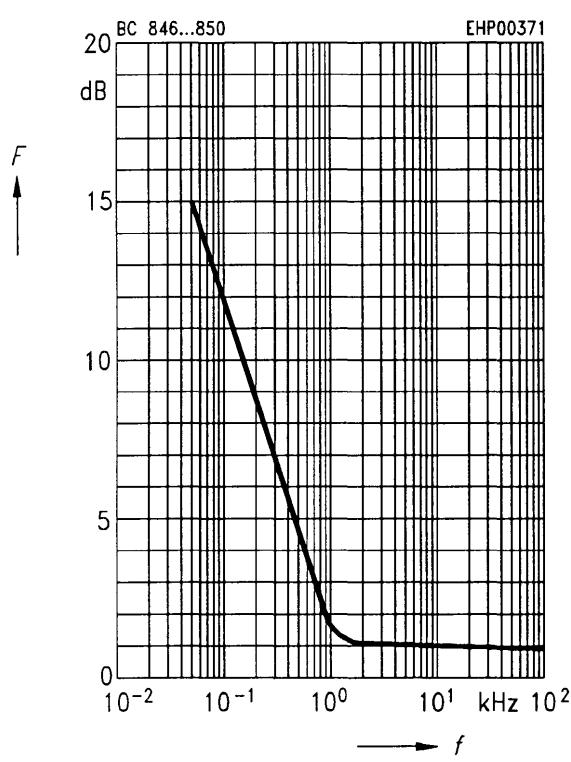
Noise figure $F = f(V_{CE})$
 $I_c = 0.2 \text{ mA}, R_s = 2 \text{ k}\Omega, f = 1 \text{ kHz}$



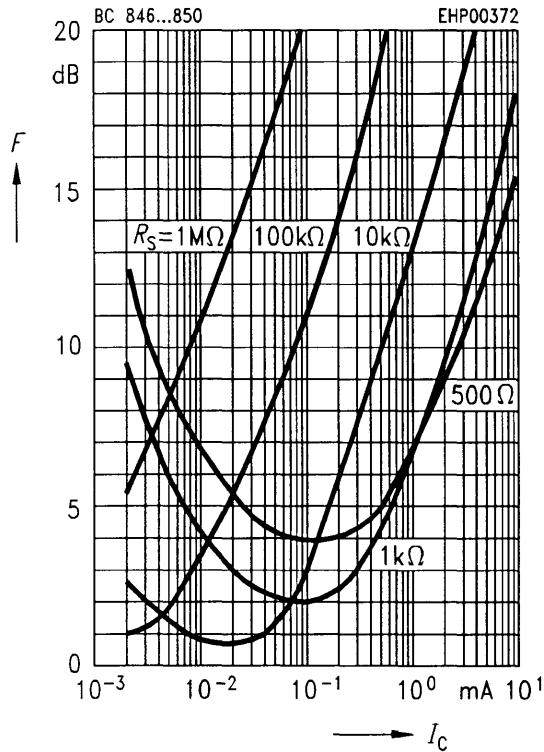
h parameter $h_e = f(V_{CE})$ normalized
 $I_c = 2 \text{ mA}$



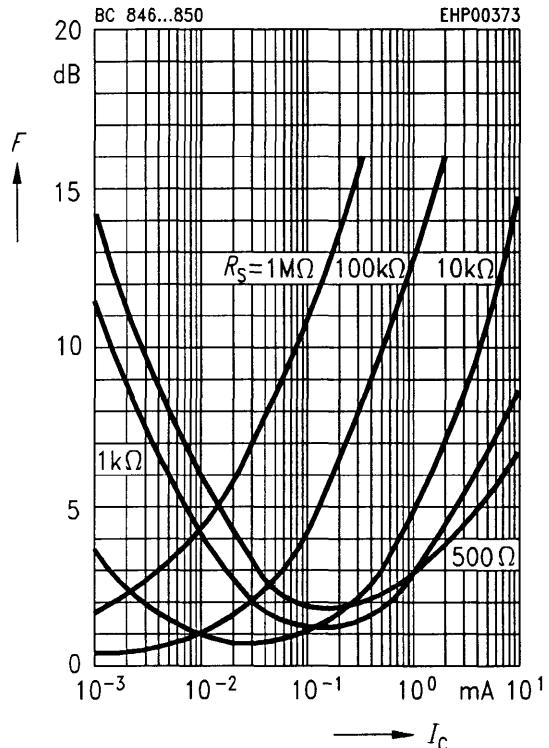
Noise figure $F = f(f)$
 $I_c = 0.2 \text{ mA}, V_{CE} = 5 \text{ V}, R_s = 2 \text{ k}\Omega$



Noise figure $F = f(I_C)$
 $V_{CE} = 5 \text{ V}, f = 120 \text{ Hz}$



Noise figure $F = f(I_C)$
 $V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$



Noise figure $F = f(I_C)$
 $V_{CE} = 5 \text{ V}, f = 10 \text{ kHz}$

